

# **QUADRACs**

### Internally Triggered Triacs (4 – 15 Amps)

#### **General Description**

Teccor's QUADRAC is a triac that includes a diac trigger mounted inside the same package. This device, developed by Teccor, saves the user the expense and assembly time of buying a discrete diac and assembling in conjunction with a gated triac.

The QUADRAC is a bidirectional AC switch and is gate controlled for either polarity of main terminal voltage. Its primary purpose is for AC switching and phase control applications such as speed controls, temperature modulation controls, and lighting controls.

Triac current capacities range from 4 to 15 Amperes with voltage ranges from 200-600 Volts. QUADRACs are available in the TO-220AB package as shown above.

The Thermotab package is electrically isolated to 2,500 V (RMS) from the leads to mounting surface. 4,000 V (RMS) available on special order. This means that no external isolation is required, thus eliminating the need for separate insulators and insulatormounting steps ... saving dollars over "hot tab" devices.

All Teccor triac and diac chips have glass-passivated junctions to ensure long term device reliability and parameter stability.

Variations of devices in this data sheet are available for custom design applications. Please consult the factory for more information.

#### **Features**

- Glass-passivated junctions
- · Electrically-isolated package
- · Internal trigger diac
- High surge capability up to 200 Amps
- High voltage capability 200 up to 600 Volts

Teccor Electronics, Inc. 3-1 QUADRACs (972) 580-7777

### **Electrical Specifications**

	Part No.		I <sub>DRM</sub>			Trigger Diac Specifications (T–MT1)						
T(RMS)	Isolated	VDRM				V <sub>TM</sub>	ΔV <sub>BO</sub>	V <sub>BO</sub>		[ΔV±]	I <sub>BO</sub>	C <sub>T</sub>
RMS On-State Current Conduction Angle of 360° (5)		Repetitive Peak Blocking Voltage (1)	Peak Off-State Current Gate Open V <sub>DRM</sub> = Max Rated Value (1) (10)			Peak On-State Voltage at Max Rated RMS Current T <sub>C</sub> = 25 °C (1) (3)	Breakover Voltage Symmetry (7)	Breakover Voltage (Forward & Reverse) (6)		Dynamic Breakback Voltage (Forward & Reverse) (6)	Peak Break- over Current	Trigger Firing Capaci- tance (11)
	∭∭ THERMOTAB TO-220AB	Volts	T <sub>C</sub> = 25°C	mAmps T <sub>C</sub> = 100°C	T <sub>C</sub> = 125°C	Volts	Volts	Volts		Volts	μ <b>A</b> mps	μFarads
	See "Package Dimensions" section for variations.		MAX		MAX	MAX	MIN	мах	MIN	MAX	MAX	
101 10	Q2004LT	MIN 200	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
4.0 Amps	Q4004LT	400	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q5004LT	500	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q6004LT	600	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q2006LT	200	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
6.0 Amps	Q4006LT	400	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
-	Q5006LT	500	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q6006LT	600	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q2008LT	200	.05	0.5	2.0	1.6	3	33 43		5	25	0.1
8.0 Amps	Q4008LT	400	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q5008LT	500	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q6008LT	600	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q2010LT	200	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
10.0 Amps	Q4010LT	400	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
•	Q5010LT	500	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q6010LT	600	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q2015LT	200	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
15.0 Amps	Q4015LT	400	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q5015LT	500	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q6015LT	600	.05	0.5	2.0	1.6	3	33	43	5	25	0.1

#### **General Notes**

- All measurements are made at 60Hz with resistive load at an ambient temperature of +25°C unless otherwise specified.
- Operating temperature range (T<sub>J</sub>) is -40°C to +125°C.
- Storage temperature range (T<sub>S</sub>) is -40°C to +125°C.
- Lead solder temperature is a maximum of +230°C for 10 seconds maximum; ≥ 1/16" (1.59mm) from case.
- The case temperature (T<sub>C</sub>) is measured as shown on dimensional outline drawings. See "Package Dimensions" section of this catalog.

#### **Electrical Specification Notes**

- (1) For either polarity of MT2 with reference to MT1.
- (2) See Figure 3.1 for  $I_H$  vs  $T_C$ .
- (3) See Figures 3.4 and 3.5 for  $i_T$  vs  $v_T$ .
- (4) See Figure 3.9 for surge ratings with specific durations.
- (5) See Figures 3.6, 3.7, and 3.8 for current rating at specific operating temperature.
- (6) See Figures 3.2 and 3.3 for test circuit.
- (7)  $\Delta V_{BO} = [+ V_{BO}] [- V_{BO}]$
- (8) See Figures 3.7 and 3.8 for maximum allowable case temperature at maximum rated current.
- (9) Trigger firing capacitance = 0.1μF with 0.1μs rise time.
- (10)  $T_C = T_J$  for test conditions in off-state.
- (11) Maximum required value to ensure sufficient gate current.

THERMAL RESISTANCE (STEADY STATE)  R <sub>0JC</sub> [R <sub>0JA(TYP)</sub> ] °C/WATT						
TYPE	ISOLATED TO-220AB					
4.0 Amps	3.6 [50]					
6.0 Amps	3.3					
8.0 Amps	2.8					
10.0 Amps	2.6					
15.0 Amps	2.1					

#### **Electrical Isolation**

All Teccor isolated QUADRAC packages will withstand a minimum high potential test of 2500VAC (RMS) from leads to mounting tab over the operating temperature range of the device. See isolation table for standard and optional isolation ratings.

ELECTRICAL FROM LEADS TO	
VAC(RMS)	TYPE
2500	Standard
4000	Optional*

<sup>\*</sup> For 4000 V isolation use "V" suffix.

<sup>\*\*</sup> U.L. Recognized File #E71639

							2			
I <sub>H</sub>	l <sub>T</sub>	SM	dv/dt(c)	dv/dt		t <sub>gt</sub>	l <sup>2</sup> t	I <sub>GTM</sub>	di/dt	
Holding Current Gate Open (1) (2)	nt Peak One Cycle Surge (4) (8)		Critical Rate-of-Rise of Commutation Voltage at Rated V <sub>DRM</sub> and I <sub>T(RMS)</sub> Commutating di/dt = 0.54 Rated I <sub>T(RMS)</sub> /ms Gate Unenergized (1) (5) (8)	Critical Rate-of- Rise of Off-State Voltage at Rated V <sub>DRM</sub> Gate Open (1) Volts/µSec		Gate Controlled Turn-On Time (6) (9)	RMS Surge (Non-Repetitive) On-State Current for period of 8.3ms for Fusing	Peak Gate Trigger Current (10µs Max)	Maximum Rate-of-Change of On-State Current (9)	
mAmps	s Amps		Volts/μSec	T <sub>C</sub> = 100°C	T <sub>C</sub> = 125°C	μSec	Amps <sup>2</sup> Sec	Amps	Amps/μSec	
MAX	60Hz	50Hz	MIN	MIN		TYP				
40	55	46	3	75	50	3	12.5	1.2	50	
40	55	46	3	75	50	3	12.5	1.2	50	
40	55	46	3	50	50	3	12.5	1.2	50	
40	55	46	3	50	50	3	12.5	1.2	50	
50	80	65	4	150	100	3	26.5	1.5	70	
50	80	65	4	150	100	3	26.5	1.5	70	
50	80	65	4	125	85	3	26.5	1.5	70	
50	80	65	4	125 85		3	26.5	1.5	70	
60	100	83	4	175 120		3	41	1.5	70	
60	100	83	4	175	120	3	41	1.5	70	
60	100	83	4	150	100	3	41	1.5	70	
60	100	83	4	150	100	3	41	1.5	70	
60	120	100	4	200	150	3	60	1.5	70	
60	120	100	4	200	150	3	60	1.5	70	
60	120	100	4	175	120	3	60	1.5	70	
60	120	100	4	175	120	3	60	1.5	70	
70	200	167	4	300	200	3	166	1.5	100	
70	200	167	4	300	200	3	166	1.5	100	
70	200	167	4	200	150	3	166	1.5	100	
70	200	167	4	200	150	3	166	1.5	100	

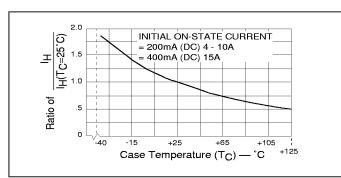


Figure 3.1 Normalized DC Holding Current vs Case Temperature

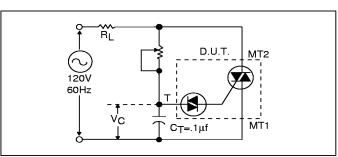


Figure 3.2 Test Circuit

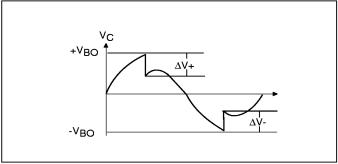
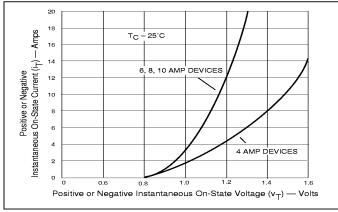
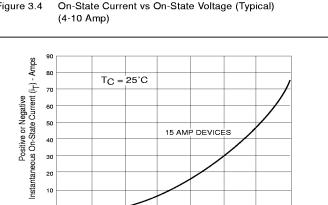


Figure 3.3 Test Circuit Waveforms

### **Electrical Specifications**





On-State Current vs On-State Voltage (Typical) (15 Amp) Figure 3.5

Positive or Negative Instantaneous On-State Voltage  $(v_T)$  - Volts

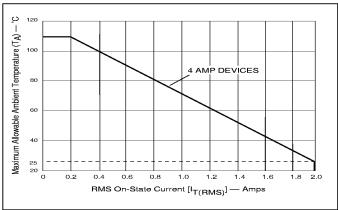


Figure 3.6 Maximum Allowable Ambient Temperature vs On-State

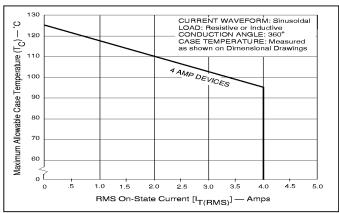


Figure 3.7 Maximum Allowable Case Temperature vs On-State Current (4 Amp)

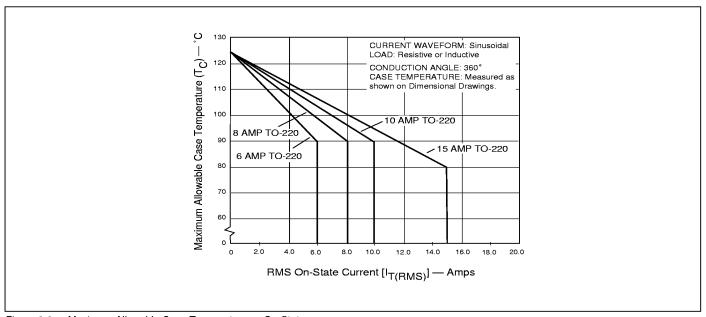


Figure 3.8 Maximum Allowable Case Temperature vs On-State Current (6-15 Amp)

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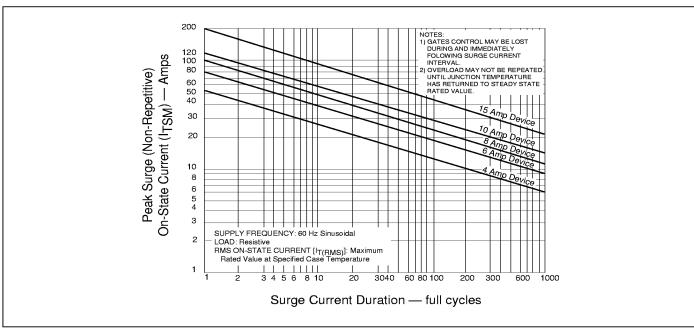


Figure 3.9 Peak Surge Current vs Surge Current Duration

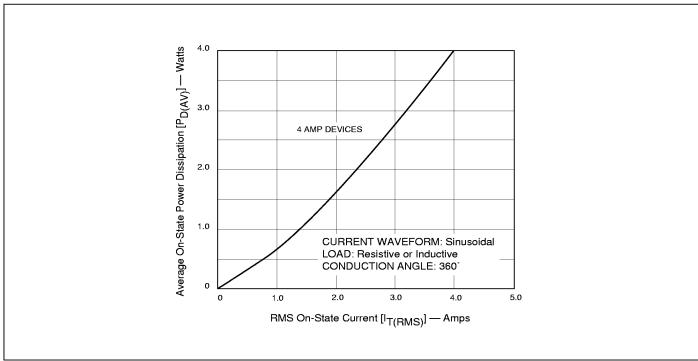


Figure 3.10 Power Dissipation (Typical) vs. On-State Current (4 Amp)

## **Electrical Specifications**

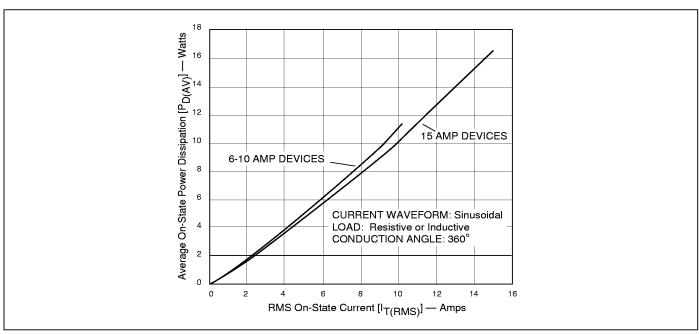


Figure 3.11 Power Dissipation (Typical) vs. On-State Current (6-10 and 15 Amp)